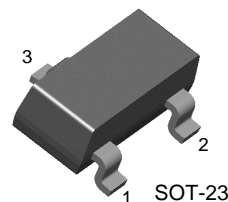


## FJV3105R

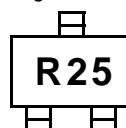
### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ( $R_1=4.7K\Omega$ ,  $R_2=10K\Omega$ )
- Complement to FJV4105R

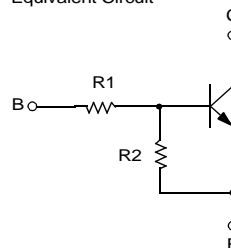


SOT-23  
1. Base 2. Emitter 3. Collector

Marking



Equivalent Circuit



### NPN Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                   | Value     | Units            |
|-----------|-----------------------------|-----------|------------------|
| $V_{CBO}$ | Collector-Base Voltage      | 50        | V                |
| $V_{CEO}$ | Collector-Emitter Voltage   | 50        | V                |
| $V_{EBO}$ | Emitter-Base Voltage        | 10        | V                |
| $I_C$     | Collector Current           | 100       | mA               |
| $P_C$     | Collector Power Dissipation | 200       | mW               |
| $T_J$     | Junction Temperature        | 150       | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature         | -55 ~ 150 | $^\circ\text{C}$ |

#### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol        | Parameter                            | Test Condition  | Min. | Typ. | Max. | Units         |
|---------------|--------------------------------------|---|------|------|------|---------------|
| $BV_{CBO}$    | Collector-Base Breakdown Voltage     | $I_C=10\mu\text{A}$ , $I_E=0$                             | 50   |      |      | V             |
| $BV_{CEO}$    | Collector-Emitter Breakdown Voltage  | $I_C=100\mu\text{A}$ , $I_B=0$                            | 50   |      |      | V             |
| $I_{CBO}$     | Collector Cut-off Current            | $V_{CB}=40\text{V}$ , $I_E=0$                             |      |      | 0.1  | $\mu\text{A}$ |
| $h_{FE}$      | DC Current Gain                      | $V_{CE}=5\text{V}$ , $I_C=5\text{mA}$                     | 30   |      |      |               |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=10\text{mA}$ , $I_B=0.5\text{mA}$                    |      |      | 0.3  | V             |
| $C_{ob}$      | Output Capacitance                   | $V_{CE}=10\text{V}$ , $I_C=5\text{mA}$<br>$f=1\text{MHz}$ |      | 3.7  |      | pF            |
| $f_T$         | Current Gain Bandwidth Product       | $V_{CE}=10\text{V}$ , $I_C=5\text{mA}$                    |      | 250  |      | MHz           |
| $V_{I(off)}$  | Input Off Voltage                    | $V_{CE}=5\text{V}$ , $I_C=100\mu\text{A}$                 | 0.3  |      |      | V             |
| $V_{I(on)}$   | Input On Voltage                     | $V_{CE}=0.3\text{V}$ , $I_C=20\text{mA}$                  |      |      | 2.5  | V             |
| $R_1$         | Input Resistor                       |   | 3.2  | 4.7  | 6.2  | $K\Omega$     |
| $R_1/R_2$     | Resistor Ratio                       |   | 0.42 | 0.47 | 0.52 |               |

# Typical Characteristics

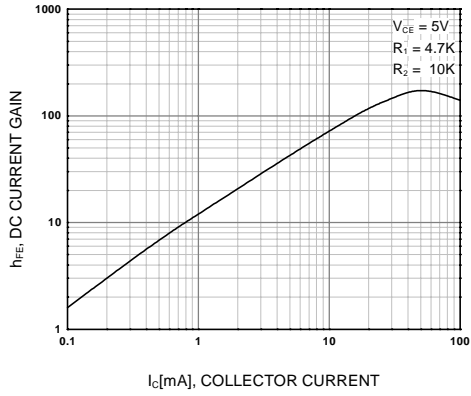


Figure 1. DC current Gain

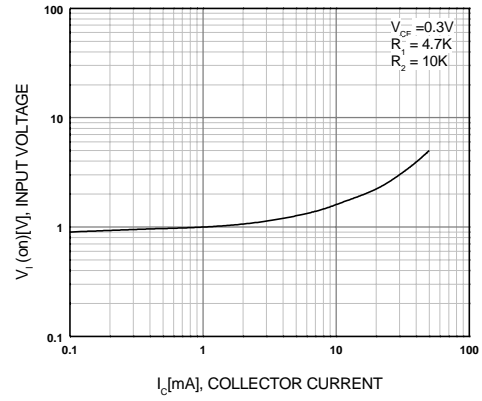


Figure 2. Input On Voltage

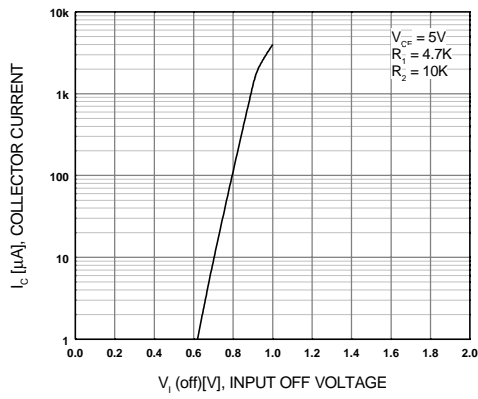


Figure 3. Input Off Voltage

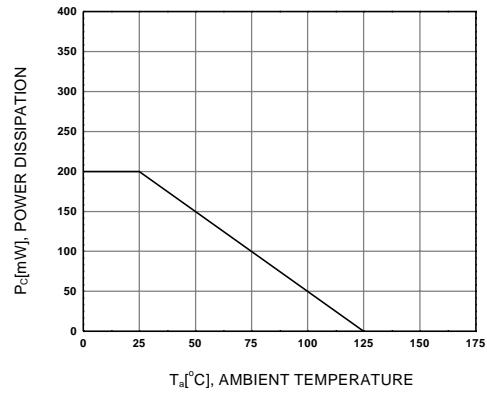


Figure 4. Power Derating

# Package Dimensions

## SOT-23



Dimensions in Millimeters

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